NSN 5962-01-424-5761

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Features Provided:
Hermetically sealed
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Ram Special Features:
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Special Features:
Special Features: 128k x 8 static ram
Special Features: 128k x 8 static ram Terminal Type And Quantity:
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life:
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life: N/a
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life: N/a Unit Of Measure:
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life: N/a Unit Of Measure:
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life: N/a Unit Of Measure: Demilitarization:
Special Features: 128k x 8 static ram Terminal Type And Quantity: 32 leadless Shelf Life: N/a Unit Of Measure: Demilitarization: No